

**FEATURES:**

- N channel FET switches with no parasitic diode to Vcc
  - Isolation under power-off conditions
  - No DC path to Vcc or GND
  - 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- Low RON - 4Ω typical
- Flat RON characteristics over operating range
- Rail-to-rail switching 0 - 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent RON matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth - up to 500 MHz
- LVTTL-compatible control Inputs
- Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- Available in SSOP and TSSOP packages

**DESCRIPTION:**

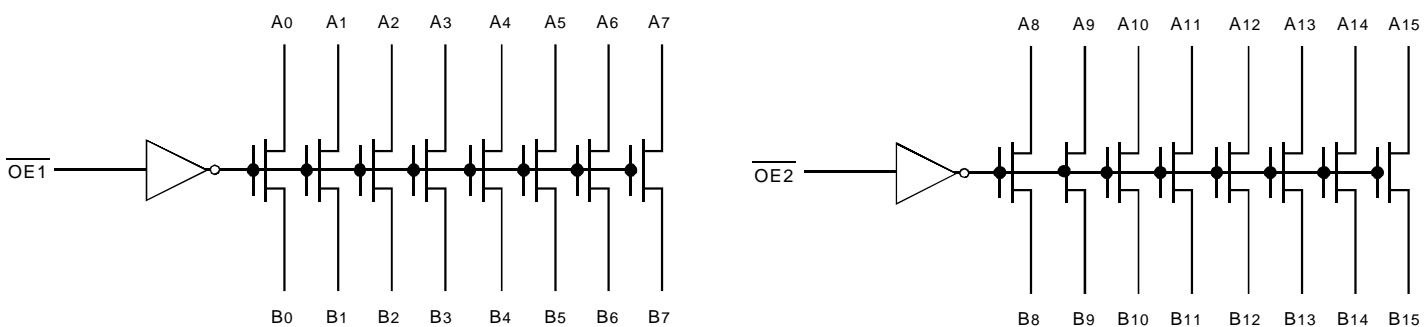
The QS3VH16245 HotSwitch is a 16-bit high bandwidth bus switch. The QS3VH16245 has very low ON resistance, resulting in under 250ps propagation delay through the switch. The switches can be turned ON under the control of the LVTTL-compatible Output Enable signals ( $\overline{OE}_1$ ) for bidirectional data flow with no added delay or ground bounce. In the ON state, the switches can pass signals up to 5V. In the OFF state, the switches offer very high impedance at the terminals.

The combination of near-zero propagation delay, high OFF impedance, and over-voltage tolerance makes the QS3VH16245 ideal for high performance communications applications.

The QS3VH16245 is characterized for operation from -40°C to +85°C.

**APPLICATIONS:**

- Hot-swapping
- 10/100 Base-T, Ethernet LAN switch
- Low distortion analog switch
- Replaces mechanical relay
- ATM 25/155 switching

**FUNCTIONAL BLOCK DIAGRAM**


## PIN CONFIGURATION

NC	1	48	OE1
B0	2	47	A0
B1	3	46	A1
GND	4	45	GND
B2	5	44	A2
B3	6	43	A3
VCC	7	42	VCC
B4	8	41	A4
B5	9	40	A5
GND	10	39	GND
B6	11	38	A6
B7	12	37	A7
B8	13	36	A8
B9	14	35	A9
GND	15	34	GND
B10	16	33	A10
B11	17	32	A11
VCC	18	31	VCC
B12	19	30	A12
B13	20	29	A13
GND	21	28	GND
B14	22	27	A14
B15	23	26	A15
NC	24	25	OE2

SSOP/ TSSOP  
TOP VIEW

## ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max.	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	-0.5 to 4.6	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to 5.5	V
VTERM <sup>(3)</sup>	DC Input Voltage Vin	-0.5 to 5.5	V
VAC	AC Input Voltage (pulse width≤20ns)	-3	V
Iout	DC Output Current (max.current/pin)	120	mA
TSTG	Storage Temperature	-65 to +150	°C

NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Vcc terminals.
3. All terminals except Vcc.

## CAPACITANCE ( $T_A = +25^{\circ}\text{C}$ , $f = 1\text{MHz}$ , $V_{IN} = 0\text{V}$ , $V_{OUT} = 0\text{V}$ )

Symbol	Parameter <sup>(1)</sup>	Typ.	Max.	Unit
C <sub>IN</sub>	Control Inputs	3	5	pF
C <sub>i/o</sub>	Quickswitch Channels (Switch OFF)	4	6	pF
C <sub>i/o</sub>	Quickswitch Channels (Switch ON)	8	12	pF

NOTE:

1. This parameter is guaranteed but not production tested.

## PIN DESCRIPTION

Pin Names	Description
OE <sub>x</sub>	Output Enables
A <sub>x</sub>	Data I/Os
B <sub>x</sub>	Data I/Os

## FUNCTION TABLE(1)

OE <sub>1</sub>	OE <sub>2</sub>	A <sub>0</sub> - A <sub>7</sub>	A <sub>8</sub> - A <sub>15</sub>	Function
L	L	B <sub>0</sub> - B <sub>7</sub>	B <sub>8</sub> - B <sub>15</sub>	Connect
L	H	B <sub>0</sub> - B <sub>7</sub>	Z	A <sub>0</sub> - A <sub>7</sub> = B <sub>0</sub> - B <sub>7</sub> , B <sub>8</sub> - B <sub>15</sub> Disconnect
H	L	Z	B <sub>8</sub> - B <sub>15</sub>	B <sub>0</sub> - B <sub>7</sub> , Disconnect, A <sub>8</sub> - A <sub>15</sub> = B <sub>8</sub> - B <sub>15</sub>
H	H	Z	Z	Disconnect

NOTE:

1. H = HIGH Voltage Level  
L = LOW Voltage Level  
Z = High-Impedance

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

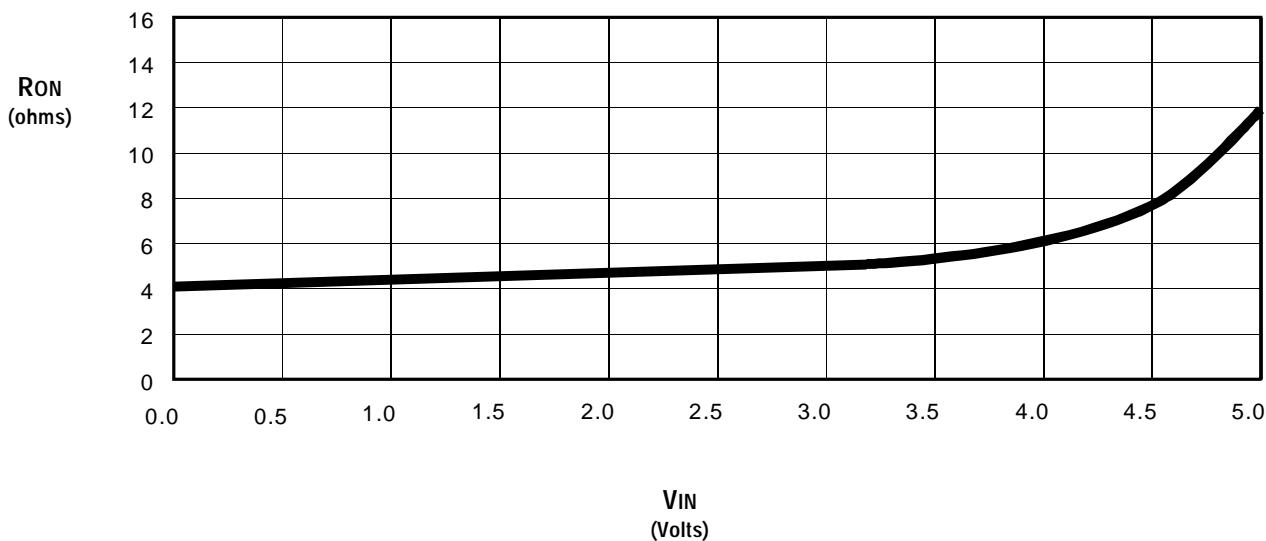
Industrial: TA = -40°C to +85°C, VCC = 3.3V ± 0.3V

Symbol	Parameter	Test Conditions			Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	VCC = 2.3V to 2.7V	—	1.7	—	—	V
			VCC = 2.7V to 3.6V	—	2	—	—	
VIL	Input LOW Voltage	Guaranteed Logic HIGH for Control Inputs	VCC = 2.3V to 2.7V	—	—	0.7	—	V
			VCC = 2.7V to 3.6V	—	—	0.8	—	
IIN	Input Leakage Current (Control Inputs)	0V ≤ VIN ≤ VCC	—	—	—	±1	μA	
IOZ	Off-State Current (Hi-Z)	0V ≤ VOUT ≤ 5V, Switches OFF	—	—	—	±1	μA	
IOFF	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, VCC = 0V	—	—	—	±1	μA	
RON	Switch ON Resistance	VCC = 2.3V (Typ. at VCC = 2.5V)	VIN = 0V	ION = 30mA	—	6	8	Ω
		VCC = 3V	VIN = 1.7V	ION = 15mA	—	7	9	
		VCC = 3V	VIN = 0V	ION = 30mA	—	4	6	
		VCC = 3V	VIN = 2.4V	ION = 15mA	—	5	8	

NOTE:

1. Typical values are at VCC = 3.3V and TA = 25°C, unless otherwise noted.

## TYPICAL ON RESISTANCE vs VIN AT VCC = 3.3V



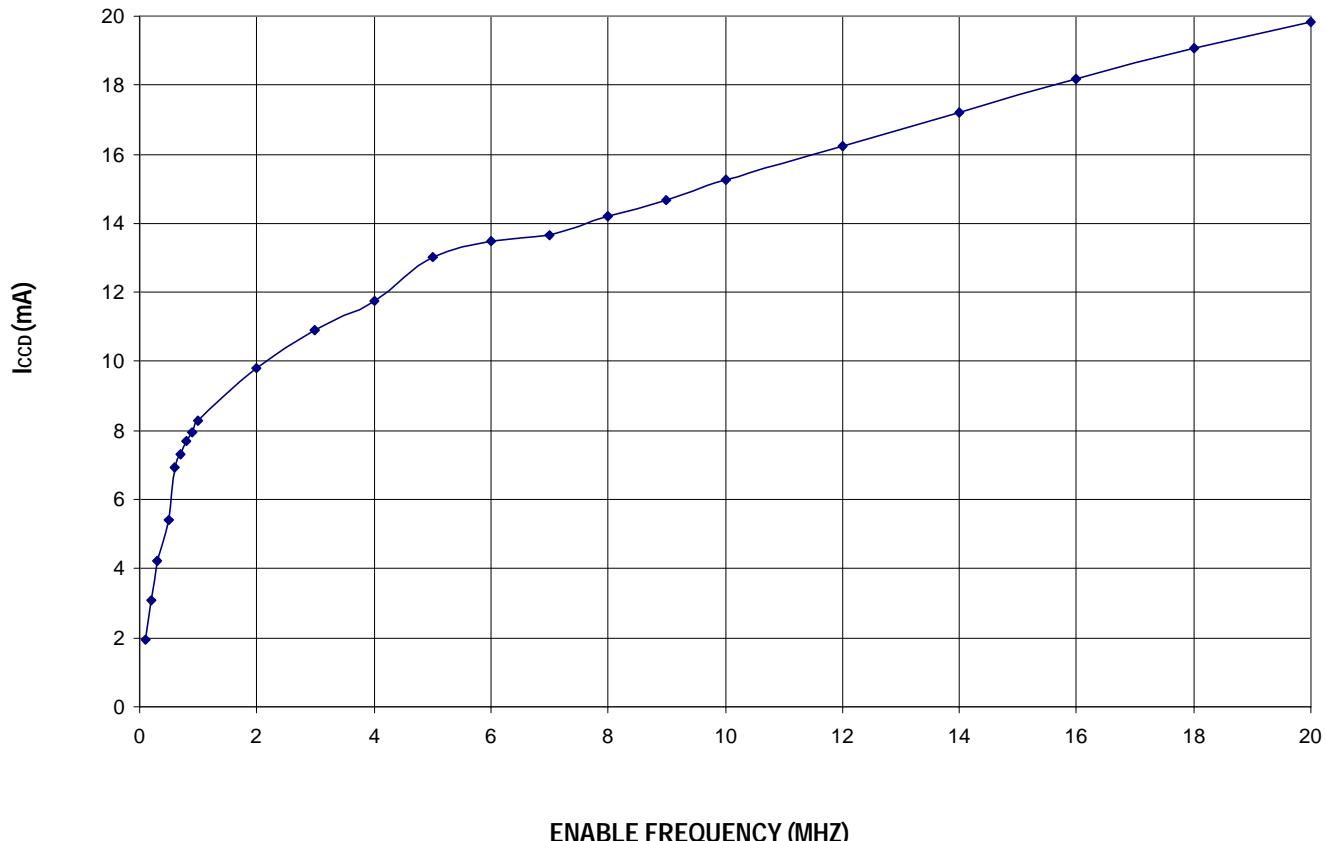
## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
I <sub>CCQ</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max., V <sub>IN</sub> = GND or V <sub>CC</sub> , f = 0	—	1.5	3	mA
ΔI <sub>CC</sub>	Power Supply Current <sup>(2,3)</sup> per Input HIGH	V <sub>CC</sub> = Max., V <sub>IN</sub> = 3V, f = 0 per Control Input	—	—	30	μA
I <sub>CCD</sub>	Dynamic Power Supply Current <sup>(4)</sup>	V <sub>CC</sub> = 3.3V, A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	See Typical I <sub>CCD</sub> vs Enable Frequency graph below			

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
2. Per input driven at the specified level. A and B pins do not contribute to ΔI<sub>CC</sub>.
3. This parameter is guaranteed but not tested.
4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

## TYPICAL I<sub>CCD</sub> VS ENABLE FREQUENCY CURVE AT V<sub>CC</sub> = 3.3V



## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

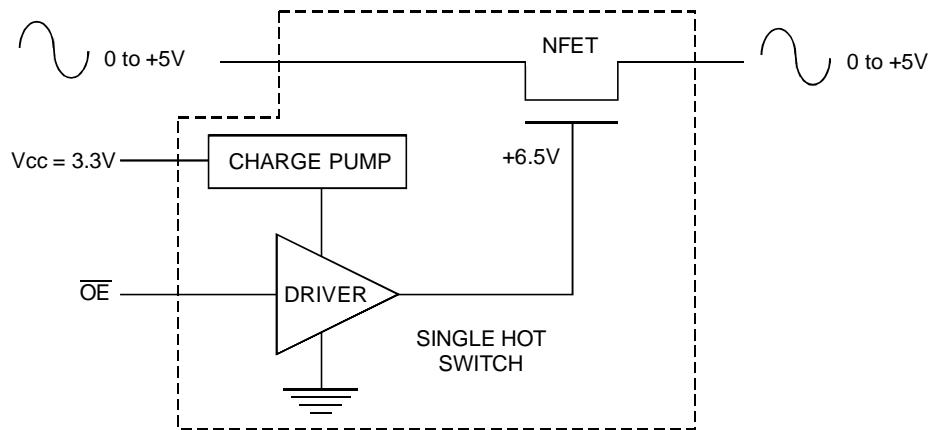
$T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$

Symbol	Parameter	$V_{CC} = 2.5 \pm 0.2\text{V}^{(1)}$		$V_{CC} = 3.3 \pm 0.3\text{V}^{(1)}$		Unit
		Min. <sup>(4)</sup>	Max.	Min. <sup>(4)</sup>	Max.	
$t_{PLH}$	Data Propagation Delay <sup>(2,3)</sup> $A_x$ to/from $B_x$	—	0.2	—	0.2	ns
$t_{PHL}$	Switch Turn-On Delay $\overline{OEx}$ to $A_x/B_x$	1.5	8	1.5	8	ns
$t_{PHZ}$	Switch Turn-Off Delay $\overline{OEx}$ to $A_x/B_x$	1.5	7.5	1.5	7.5	ns
$f_{OEx}$	Operating Frequency-Enable <sup>(2,5)</sup>	—	10	—	20	MHz

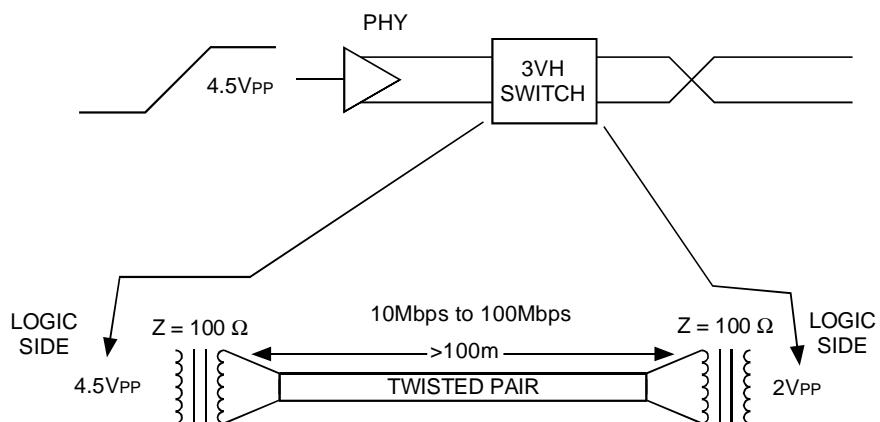
### NOTES:

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.
2. This parameter is guaranteed but not production tested.
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at  $C_L = 50\text{pF}$ . Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
4. Minimums are guaranteed but not production tested.
5. Maximum toggle frequency for  $\overline{OEx}$  control input (pass voltage >  $V_{CC}$ ,  $V_{IN} = 5\text{V}$ ,  $R_{LOAD} \geq 1\text{M}\Omega$ , no  $C_{LOAD}$ ).

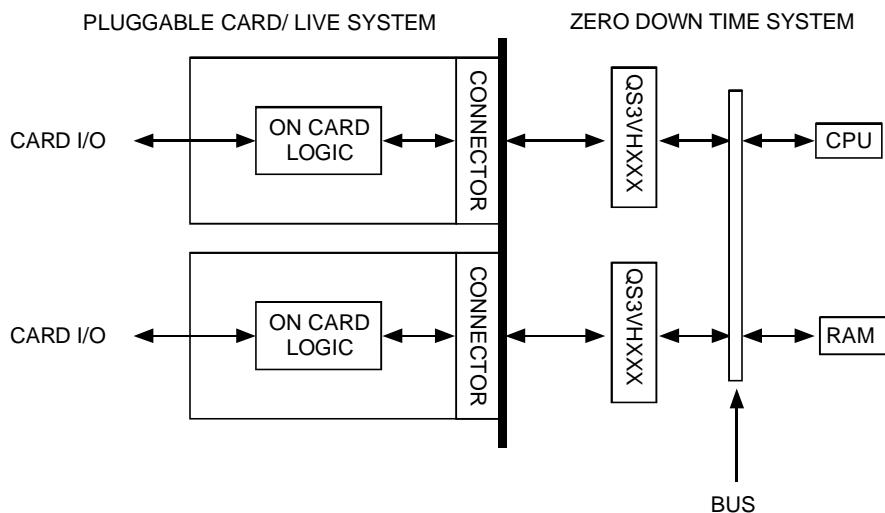
## SOME APPLICATIONS FOR HOTSWITCH PRODUCTS



*Rail-to-Rail Switching*



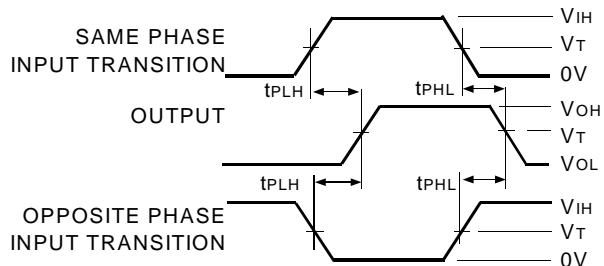
*Fast Ethernet Data Switching (LAN Switch)*



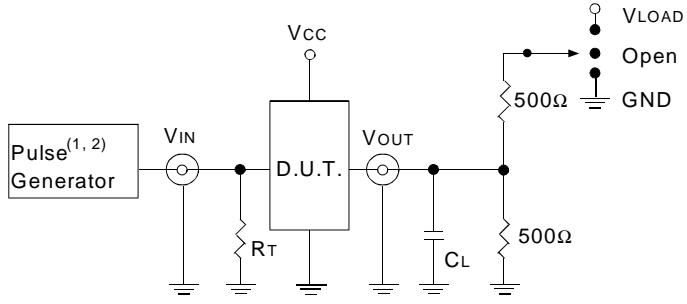
## TEST CIRCUITS AND WAVEFORMS

### TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
$V_{LOAD}$	6	$2 \times V_{CC}$	V
$V_{IH}$	3	$V_{CC}$	V
$V_T$	1.5	$V_{CC}/2$	V
$V_{LZ}$	300	150	mV
$V_{HZ}$	300	150	mV
$C_L$	50	30	pF



Propagation Delay



Test Circuits for All Outputs

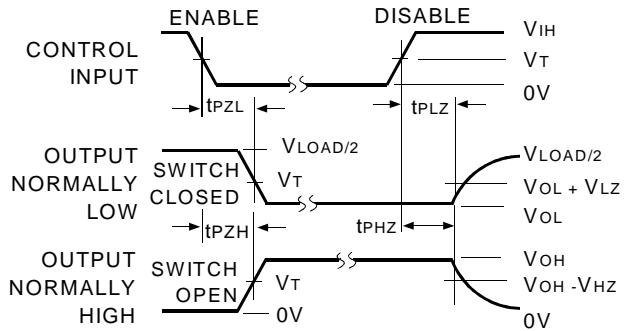
### DEFINITIONS:

$CL$  = Load capacitance: includes jig and probe capacitance.

$R_T$  = Termination resistance: should be equal to  $Z_{out}$  of the Pulse Generator.

### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq 1.0\text{MHz}$ ;  $t_f \leq 2.5\text{ns}$ ;  $t_r \leq 2.5\text{ns}$ .
2. Pulse Generator for All Pulses: Rate  $\leq 1.0\text{MHz}$ ;  $t_f \leq 2\text{ns}$ ;  $t_r \leq 2\text{ns}$ .



### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

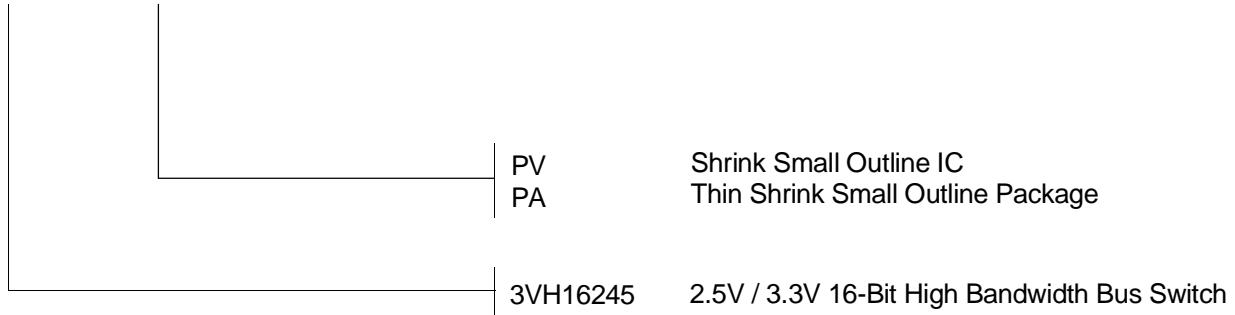
Enable and Disable Times

## SWITCH POSITION

Test	Switch
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND
$t_{PD}$	Open

## ORDERING INFORMATION

IDTQS XXXXX XX  
Device Type Package



**CORPORATE HEADQUARTERS**  
2975 Stender Way  
Santa Clara, CA 95054

*for SALES:*  
800-345-7015 or 408-727-6116  
fax: 408-492-8674  
[www.idt.com](http://www.idt.com)

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(408) 654-6459